NSN 5961-01-007-0121

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-007-0121 **Inclosure Material:** Metal **Overall Length:** 2.637 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Overall Width Across Flats:** 1.063 inches **Thread Size:** 0.500 inches **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1300.0 nonrepetitive peak reverse voltage, peak total value and 1200.0 repetitive peak reverse voltage, peak total value **Current Rating Per Characteristic:** 1200.00 amperes source cutoff current peak and 110.00 amperes forward current, average megahertz **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector blank and 2.0 watts small-signal input power, common-collector universal **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Weapon system essential **Test Data Document:** 10001-2887706 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No